Vishay Semiconductors

# High Performance Schottky Rectifier, 1 A



<u> </u>	
Cathode	Anode
o—	 0

DO-214AC (SMA)

PRODUCT SUMMARY				
Package	DO-214AC (SMA)			
I <sub>F(AV)</sub>	1 A			
V <sub>R</sub>	40 V			
V <sub>F</sub> at I <sub>F</sub>	0.49 V			
I <sub>RM</sub>	26 mA at 125 °C			
T <sub>J</sub> max.	150 °C			
Diode variation	Single die			
E <sub>AS</sub>	3.0 mJ			

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### **FEATURES**

• Low forward voltage drop



RoHS

COMPLIANT

- Guard ring for enhanced ruggedness and long term reliability
- Small foot print, surface mountable
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### DESCRIPTION

The VS-MBRA140TRPbF surface mount Schottky rectifier has been designed for applications requiring low forward drop and very small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL	CHARACTERISTICS	CHARACTERISTICS VALUES UNITS						
I <sub>F(AV)</sub>	Rectangular waveform	1	A					
V <sub>RRM</sub>		40	V					
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	120	A					
V <sub>F</sub>	1.5 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.56	V					
TJ	Range	-55 to +150	°C					

VOLTAGE RATINGS					
PARAMETER	SYMBOL	VS-MBRA140TRPBF	UNITS		
Maximum DC reverse voltage	V <sub>R</sub>	40	V		
Maximum working peak reverse voltage	V <sub>RWM</sub>	40	v		

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDI	TIONS	VALUES	UNITS
Maximum average forward current		50 % duty cycle at $T_L$ = 123 °C, n On PC board 9 mm <sup>2</sup> island (0.013 mm thick copper pad area	C C	1.5	А
See fig. 4		50 % duty cycle at $T_L$ = 132 °C, rectangular waveform On PC board 9 mm <sup>2</sup> island (0.013 mm thick copper pad area)		1	A
Maximum peak one cycle non-repetitive surge current		5 µs sine or 3 µs rect. pulse	Following any rated load condition and with	120	А
See fig. 6	I <sub>FSM</sub>	10 ms sine or 6 ms rect. pulse	rated V <sub>RRM</sub> applied	30	~
Non-repetitive avalanche energy	E <sub>AS</sub>	$T_J = 25 \text{ °C}, I_{AS} = 1 \text{ A}, L = 6 \text{ mH}$		3.0	mJ
Repetitive avalanche current	I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ s Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical		1.0	А

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# **VS-MBRA140TRPbF**



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ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS	
		1 A	T <sub>.1</sub> = 25 °C	0.54	V	
Maximum forward voltage drop	V <sub>FM</sub> <sup>(1)</sup>	1.5 A	1j=25 0	0.62		
See fig. 1	VFM (*)	1 A	T - 125 °C	0.49	v	
		1.5 A	T <sub>J</sub> = 125 °C	0.56		
Maximum reverse leakage current		T <sub>J</sub> = 25 °C	V <sub>R</sub> = Rated V <sub>R</sub>	0.5	mA	
See fig. 2	I <sub>RM</sub>	T <sub>J</sub> = 125 °C		26		
Threshold voltage	V <sub>F(TO)</sub>	$T_J = T_J maximum$		0.36	V	
Forward slope resistance	r <sub>t</sub>			104	mΩ	
Typical junction capacitance	CT	$V_R = 10 V_{DC}$ , $T_J = 25 \text{ °C}$ , test signal = 1 MHz 38		pF		
Typical series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body 2.0		nH		
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub> 10 000		V/µs		

#### Note

 $^{(1)}$  Pulse width = 300  $\mu s,$  duty cycle = 2 %

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range	T <sub>J</sub> <sup>(1)</sup> , T <sub>Stg</sub>		-55 to +150	°C	
Maximum thermal resistance, junction to ambient	R <sub>thJA</sub>	DC operation	80	°C/W	
Approximate weight			0.07	g	
Approximate weight			0.002	oz.	
Marking device		Case style SMA (similar D-64)	1	F	

#### Note

 $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$  thermal runaway condition for a diode on its own heatsink (1)



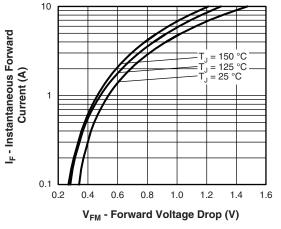
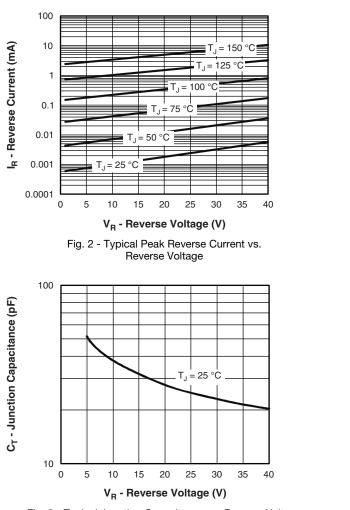
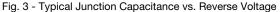


Fig. 1 - Maximum Forward Voltage Drop Characteristics





## VS-MBRA140TRPbF

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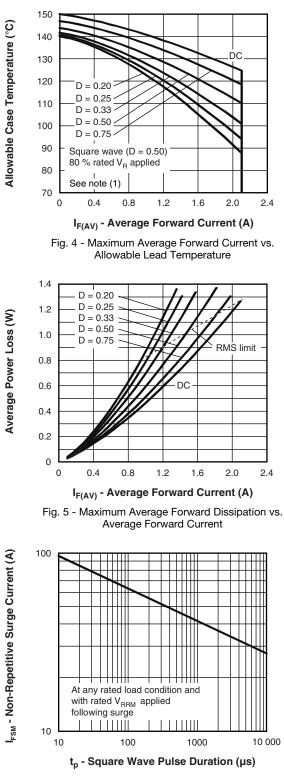


Fig. 6 - Maximum Peak Surge Forward Current vs. Pulse Duration

#### Note

<sup>(1)</sup> Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;

Pd = Forward power loss = I<sub>F(AV)</sub> x V<sub>FM</sub> at (I<sub>F(AV)</sub>/D) (see fig. 6); Pd<sub>REV</sub> = Inverse power loss = V<sub>R1</sub> x I<sub>R</sub> (1 - D); I<sub>R</sub> at V<sub>R1</sub> = 80 % rated V<sub>R</sub>

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## Vishay Semiconductors



### **ORDERING INFORMATION TABLE**

Device code	VS-	MBR	Α	1	40	TR	PbF
		2	3	4	5	6	7
	1 .	- Visł	nay Sem	niconduc	tors pro	oduct	
	2 - Schottky MBR series						
	3 - A = SMA						
	4	4 - Current rating (1 = 1A)					
	5 -	- Voli	tage rati	ng (40 =	40 V)		
	6	TR	= tape a	and reel	(7500 p	ocs)	
	7	PbF = terminations lead (Pb)-free					

ORDERING INFORMATION (Example)						
PREFERRED P/N	PREFERRED PACKAGE CODE MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION					
VS-MBRA140TRPbF	5AT	7500	13" diameter plastic tape and reel			

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95400			
Part marking information	www.vishay.com/doc?95403			
Packaging information	www.vishay.com/doc?95404			



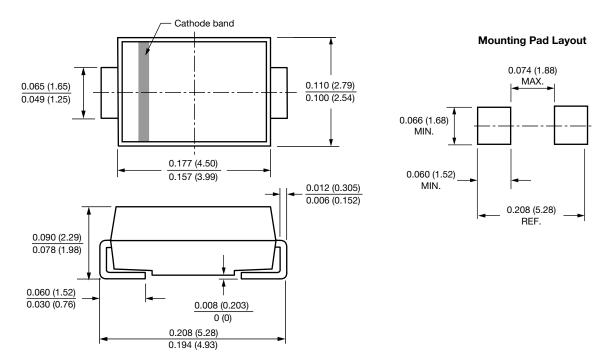
## **Outline Dimensions**

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SMA

### **DIMENSIONS** in inches (millimeters)

DO-214AC (SMA)





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